

CMOS Low Voltage 2.5 Ω Dual SPDT Switch

Data Sheet ADG736

FEATURES

1.8 V to 5.5 V single supply Automotive temperature range: -40° C to $+125^{\circ}$ C 2.5 Ω (typical) on resistance Low on resistance flatness -3 dB bandwidth > 200 MHz Rail-to-rail operation 10-lead MSOP package Fast switching times

ton: 16 ns toff: 8 ns

Typical power consumption (<0.01 μW)
TTL-/CMOS-compatible
Qualified for automotive applications

APPLICATIONS

USB 1.1 signal switching circuits
Cell phones
PDAs
Battery-powered systems
Communications systems
Sample-and-hold systems
Audio signal routing
Audio and video switching
Mechanical reed relay replacement

GENERAL DESCRIPTION

The ADG736 is a monolithic device comprising two independently selectable CMOS single pole, double throw (SPDT) switches. These switches are designed using a submicron process that provides low power dissipation yet gives high switching speed, low on resistance, low leakage currents, and wide input signal bandwidth.

The on resistance profile is very flat over the full analog signal range. This ensures excellent linearity and low distortion when switching audio signals. Fast switching speed also makes the part suitable for video signal switching.

The ADG736 operates from a single 1.8 V to 5.5 V supply, making it ideally suited to portable and battery-powered instruments.

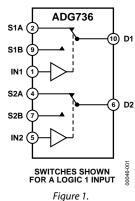
Each switch conducts equally well in both directions when on, and each has an input signal range that extends to the power supplies. The ADG736 exhibits break-before-make switching action.

The ADG736 is available in a 10-lead MSOP package.

Rev. D

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FUNCTIONAL BLOCK DIAGRAM



PRODUCT HIGHLIGHTS

- 1.8 V to 5.5 V Single-Supply Operation. The ADG736
 offers high performance, including low on resistance and
 fast switching times. It is fully specified and guaranteed
 with 3 V and 5 V supply rails.
- 2. Very Low R_{ON} (4.5 Ω Maximum at 5 V, 8 Ω Maximum at 3 V). At a supply voltage of 1.8 V, R_{ON} is typically 35 Ω over the temperature range.
- 3. Low On Resistance Flatness.
- 4. -3 dB Bandwidth > 200 MHz.
- 5. Low Power Dissipation. CMOS construction ensures low power dissipation.
- 6. Fast ton/toff.
- 7. Break-Before-Make Switching Action.
- 8. 10-Lead MSOP Package.

ADG736* Product Page Quick Links

Last Content Update: 11/01/2016

Comparable Parts

View a parametric search of comparable parts

Evaluation Kits <a> □

• Evaluation Board for 10-Lead MSOP Devices in the Switches and Multiplexers Portfolio

Documentation <a>□

Data Sheet

• ADG736: CMOS Low Voltage 2.5 Ω Dual SPDT Switch Data Sheet

User Guides

 UG-1037: Evaluation Board for 10-Lead MSOP Devices in the Switches and Multiplexers Portfolio

Reference Materials

Product Selection Guide

• Switches and Multiplexers Product Selection Guide

Technical Articles

- CMOS Switches Offer High Performance in Low Power, Wideband Applications
- · Data-acquisition system uses fault protection
- Enhanced Multiplexing for MEMS Optical Cross Connects
- Temperature monitor measures three thermal zones

Design Resources <a>□

- ADG736 Material Declaration
- · PCN-PDN Information
- · Quality And Reliability
- · Symbols and Footprints

Discussions <a>□

View all ADG736 EngineerZone Discussions

Sample and Buy <a> □

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Technical Support -

Submit a technical question or find your regional support number

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Added Automotive Information (Throughout)
12/07—Rev. B to Rev. C
Updated Temperature Range (Throughout)
1/07—Rev. A to Rev. B
Updated Format Universal Changes to Leakage Currents 3 Changes to Leakage Currents 4 Changes to Ordering Guide 12 Updated Outline Dimensions 12
11/03—Rev. 0 to Rev. A
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SPECIFICATIONS

 V_{DD} = 5 V \pm 10%, GND = 0 V. All specifications –40°C to +125°C, unless otherwise noted.

Table 1.

	B Version					
	-40°C to -40°C to		−40°C to			
Parameter	25°C	+85°C	+125°C	Unit	Test Conditions/Comments	
ANALOG SWITCH						
Analog Signal Range			$0 V to V_{DD}$	V		
On Resistance (R _{ON})	2.5			Ωtyp	$V_S = 0 \text{ V to } V_{DD}$, $I_{DS} = -10 \text{ mA}$; see Figure 10	
	4	4.5	7	Ω max		
On Resistance Match Between Channels (ΔR_{ON})	0.1			Ωtyp	$V_S = 0 V \text{ to } V_{DD}$, $I_{DS} = -10 \text{ mA}$	
		0.4	0.4	Ω max		
On Resistance Flatness (R _{FLAT (ON)})	0.5			Ωtyp	$V_S = 0 V \text{ to } V_{DD}$, $I_{DS} = -10 \text{ mA}$	
		1.2	1.5	Ω max		
LEAKAGE CURRENTS					$V_{DD} = 5.5 \text{ V}$	
Source Off Leakage I₅ (Off)	±0.01		1	nA typ	$V_S = 4.5 \text{ V/1 V}, V_D = 1 \text{ V/4.5 V};$ see Figure 11	
Channel On Leakage ID, Is (On)	±0.01		5	nA typ	$V_S = V_D = 1 \text{ V or } 4.5 \text{ V}$; see Figure 12	
DIGITAL INPUTS						
Input High Voltage, V _{INH}		2.4	2.4	V min		
Input Low Voltage, V _{INL}		0.8	0.8	V max		
Input Current, I _{INL} or I _{INH}	0.005			μA typ	$V_{\text{IN}} = V_{\text{INL}} \text{ or } V_{\text{INH}}$	
		± 0.1	± 0.1	μA max		
DYNAMIC CHARACTERISTICS ¹						
t _{ON}	12			ns typ	$R_L = 300 \Omega$, $C_L = 35 pF$	
		16	16	ns max	$V_s = 3 V$; see Figure 13	
toff	5			ns typ	$R_L = 300 \Omega$, $C_L = 35 pF$	
		8	8	ns max	$V_S = 3 V$; see Figure 13	
Break-Before-Make Time Delay, t _D	7			ns typ	$R_L = 300 \Omega$, $C_L = 35 pF$	
		1	1	ns min	$V_{S1} = V_{S2} = 3 \text{ V}$; see Figure 14	
Off Isolation	-62			dB typ	$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 10 MHz$	
	-82			dB typ	$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 1 MHz$; see Figure 15	
Channel-to-Channel Crosstalk	-62			dB typ	$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 10 MHz$	
	-82			dB typ	$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 1 MHz$; see Figure 16	
Bandwidth (–3 dB)	200			MHz typ	$R_L = 50 \Omega$, $C_L = 5 pF$; see Figure 17	
C _s (Off)	9			pF typ		
C_D , C_S (On)	32			pF typ		
POWER REQUIREMENTS					V _{DD} = 5.5 V	
I_{DD}	0.001			μA typ	Digital inputs = 0 V or 5 V	
		1.0	1.0	μA max		

 $^{^{\}mbox{\tiny 1}}$ Guaranteed by design; not subject to production test.

 V_{DD} = 3 V \pm 10%, GND = 0 V. All specifications –40°C to +125°C, unless otherwise noted.

Table 2.

		B Version				
	−40°C to −40°C to		−40°C to			
Parameter	25°C	+85°C	+125°C	Unit	Test Conditions/Comments	
ANALOG SWITCH						
Analog Signal Range			$0V$ to V_{DD}	V		
On Resistance (R _{ON})	5	5.5		Ωtyp	$V_S = 0 \text{ V to } V_{DD}$, $I_{DS} = -10 \text{ mA}$; see Figure 10	
		8	12	Ω max	See Figure 10	
On Resistance Match Between Channels (ΔR_{ON})	0.1			Ωtyp	$V_S = 0 \text{ V to } V_{DD}, I_{DS} = -10 \text{ mA}$	
		0.4	0.4	Ω max		
On Resistance Flatness (R _{FLAT (ON)})		2.5	2.5	Ωtyp	$V_S = 0 \text{ V to } V_{DD}, I_{DS} = -10 \text{ mA}$	
LEAKAGE CURRENTS					$V_{DD} = 3.3 \text{ V}$	
Source Off Leakage Is (Off)	±0.01		1	nA typ	$V_S = 3 \text{ V}/1 \text{ V}, V_D = 1 \text{ V}/3 \text{ V};$ see Figure 11	
Channel On Leakage I _D , I _S (On)	±0.01		5	nA typ	$V_S = V_D = 1 \text{ V or } 3 \text{ V}$; see Figure 12	
DIGITAL INPUTS						
Input High Voltage, V _{INH}		2.0	2.4	V min		
Input Low Voltage, V _{INL}		0.4	0.8	V max		
Input Current, I _{INL} or I _{INH}	0.005			μA typ	$V_{IN} = V_{INL} \text{ or } V_{INH}$	
		±0.1	± 0.1	μA max		
DYNAMIC CHARACTERISTICS ¹						
ton	14			ns typ	$R_L = 300 \Omega$, $C_L = 35 pF$	
		20	20	ns max	V _s = 2 V; see Figure 13	
t _{OFF}	6			ns typ	$R_L = 300 \Omega$, $C_L = 35 pF$	
		10	10	ns max	$V_s = 2 V$; see Figure 13	
Break-Before-Make Time Delay, t _D	7			ns typ	$R_L = 300 \Omega, C_L = 35 pF$	
		1	1	ns min	$V_{S1} = V_{S2} = 2 \text{ V}$; see Figure 14	
Off Isolation	-62			dB typ	$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 10 MHz$	
	-82			dB typ	$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 1 MHz$; see Figure 15	
Channel-to-Channel Crosstalk	-62			dB typ	$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 10 MHz$	
	-82			dB typ	$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 1 MHz$; see Figure 16	
Bandwidth (–3 dB)	200			MHz typ	$R_L = 50 \Omega$, $C_L = 5 pF$; see Figure 17	
C _s (Off)	9			pF typ		
C _D , C _s (On)	32			pF typ		
POWER REQUIREMENTS				1. /	$V_{DD} = 3.3 \text{ V}$	
I_{DD}	0.001			μA typ	Digital inputs = 0 V or 3 V	
		1.0	1.0	μA max		

 $^{^{\}rm 1}\,\mbox{Guaranteed}$ by design; not subject to production test.

ABSOLUTE MAXIMUM RATINGS

 $T_A = 25$ °C, unless otherwise noted.

Table 3

Table 3.	
Parameter	Rating
V _{DD} to GND	−0.3 V to +6 V
Analog, Digital Inputs ¹	$-0.3 \text{ V to V}_{DD} + 0.3 \text{ V or } 30 \text{ mA},$ whichever occurs first
Continuous Current, S or D	30 mA
Peak Current, S or D	100 mA (Pulsed at 1 ms, 10% duty cycle maximum)
Operating Temperature Range	
Automotive	−40°C to +125°C
Storage Temperature Range	−65°C to +150°C
Junction Temperature	150°C
MSOP Package, Power Dissipation	315 mW
θ_{JA} Thermal Impedance	205°C/W
Lead Temperature (Soldering, 10 sec)	300°C
IR Reflow (Peak Temperature, <20 sec)	235°C
Lead-Free Reflow Soldering	
Peak Temperature	260(+0/-5)°C
Time at Peak Temperature	10 sec to 40 sec
ESD	2 kV

¹ Overvoltages at IN, S, or D are clamped by internal diodes. Current should be limited to the maximum ratings given.

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

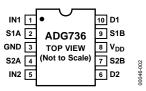


Figure 2. Pin Configuration

Table 4. Pin Function Descriptions

1 4010 10 1111 1							
Pin No.	Mnemonic	Description					
1	IN1	Logic Control Input.					
2	S1A	Source Terminal. May be an input or output.					
3	GND	Ground (0 V) Reference.					
4	S2A	Source Terminal. May be an input or output.					
5	IN2	Logic Control Input.					
6	D2	Drain Terminal. May be an input or output.					
7	S2B	Source Terminal. May be an input or output.					
8	V_{DD}	Most Positive Power Supply Potential.					
9	S1B	Source Terminal. May be an input or output.					
10	D1	Drain Terminal. May be an input or output.					

Table 5. Truth Table

Logic	Switch A	Switch B
0	Off	On
1	On	Off

TYPICAL PERFORMANCE CHARACTERISTICS

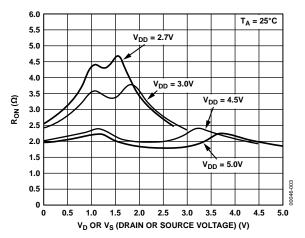


Figure 3. On Resistance as a Function of V_D or V_S Single Supplies

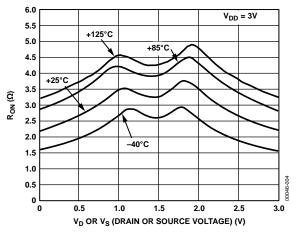


Figure 4. On Resistance as a Function of V_D or V_S for Different Temperatures $V_{DD} = 3~V$

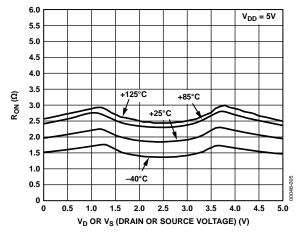


Figure 5. On Resistance as a Function of V_D or V_S for Different Temperatures $V_{DD} = 5~V$

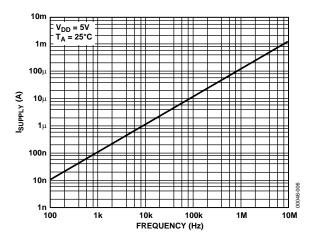


Figure 6. Supply Current vs. Input Switching Frequency

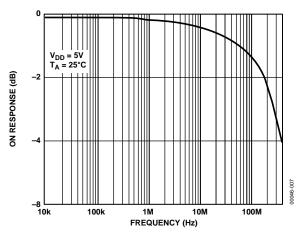


Figure 7. Bandwidth

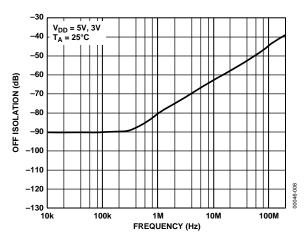


Figure 8. Off Isolation vs. Frequency

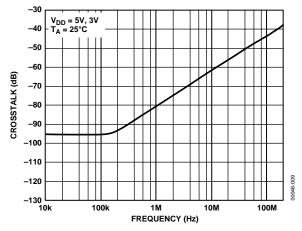


Figure 9. Crosstalk vs. Frequency

TEST CIRCUITS

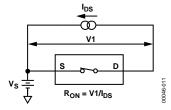


Figure 10. On Resistance

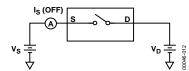


Figure 11. Off Leakage

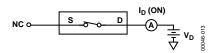


Figure 12. On Leakage

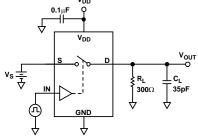
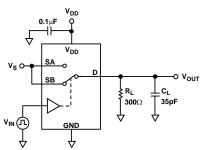


Figure 13. Switching Times



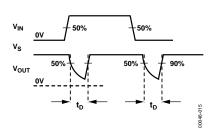


Figure 14. Break-Before-Make Time Delay, t_D

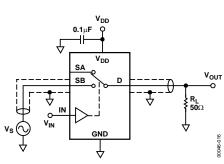


Figure 15. Off Isolation

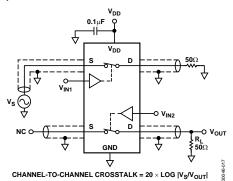


Figure 16. Channel-to-Channel Crosstalk

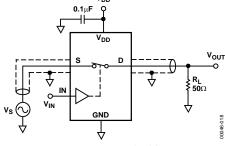


Figure 17. Bandwidth

TERMINOLOGY

Ron

Ohmic resistance between Terminal D and Terminal S.

ΔR_{ON}

On resistance match between any two channels; that is, $R_{\rm ON}$ maximum – $R_{\rm ON}$ minimum.

R_{FLAT} (ON)

Flatness is defined as the difference between the maximum and minimum value of on resistance as measured over the specified analog signal range.

Is (Off)

Source leakage current with the switch off.

I_D , I_S (On)

Channel leakage current with the switch on.

$V_D(V_S)$

Analog voltage on Terminal D and Terminal S.

C_s (Off)

Off switch source capacitance.

C_D , C_S (On)

On switch capacitance.

ton

Delay between applying the digital control input and the output switching on. See Figure 13.

ton

Delay between applying the digital control input and the output switching off. See Figure 13.

tn

Off time or on time measured between the 90% points of both switches, when switching from one address state to another. See Figure 14.

Crosstalk

A measure of unwanted signal that is coupled from one channel to another as a result of parasitic capacitance.

Off Isolation

A measure of unwanted signal coupling through an off switch.

Randwidth

The frequency at which the output is attenuated by -3 dB.

On Response

The frequency response of the on switch.

On Loss

The voltage drop across the on switch, seen on the on response vs. frequency plot (see Figure 7) as how many decibels (dB) the signal is away from 0 dB at very low frequencies.

APPLICATIONS INFORMATION

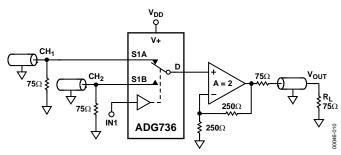


Figure 18. Using the ADG736 to Select Between Two Video Signals

OUTLINE DIMENSIONS

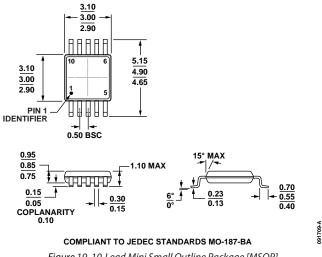


Figure 19. 10-Lead Mini Small Outline Package [MSOP] (RM-10) Dimensions shown in millimeters

ORDERING GUIDE

Model ^{1, 2}	Temperature Range	Package Description	Package Option	Branding
ADG736BRM	-40°C to +125°C	10-Lead Mini Small Outline Package (MSOP)	RM-10	SAB
ADG736BRM-REEL	-40°C to +125°C	10-Lead Mini Small Outline Package (MSOP)	RM-10	SAB
ADG736BRM-REEL7	-40°C to +125°C	10-Lead Mini Small Outline Package (MSOP)	RM-10	SAB
ADG736BRMZ	-40°C to +125°C	10-Lead Mini Small Outline Package (MSOP)	RM-10	SAB#
ADG736BRMZ-REEL	-40°C to +125°C	10-Lead Mini Small Outline Package (MSOP)	RM-10	SAB#
ADG736BRMZ-REEL7	-40°C to +125°C	10-Lead Mini Small Outline Package (MSOP)	RM-10	SAB#
ADW54010Z-0REEL	-40°C to +125°C	10-Lead Mini Small Outline Package (MSOP)	RM-10	SAB#

 $^{^{1}}$ Z = RoHS Compliant Part, # denotes RoHS compliant part may be top or bottom marked.

AUTOMOTIVE PRODUCTS

The ADW54010Z model is available with controlled manufacturing to support the quality and reliability requirements of automotive applications. Note that these automotive models may have specifications that differ from the commercial models; therefore, designers should review the Specifications section of this data sheet carefully. Only the automotive grade products shown are available for use in automotive applications. Contact your local Analog Devices account representative for specific product ordering information and to obtain the specific Automotive Reliability reports for these models.

 $^{^{2}}$ W = Qualified for Automotive Applications.